

RF Power MOSFET Transistor
40W, 100-500 MHz, 28V
M/A-COM Products
Released; RoHS Compliant
Features

- N-channel enhancement mode device
- DMOS structure
- Lower capacitances for broadband operation
- Common source configuration
- Lower noise floor

ABSOLUTE MAXIMUM RATINGS AT 25° C

Parameter	Symbol	Rating	Units
Drain-Source Voltage	V_{DS}	65	V
Gate-Source Voltage	V_{GS}	20	V
Drain-Source Current	I_{DS}	4*	A
Power Dissipation	P_D	116	W
Junction Temperature	T_J	200	°C
Storage Temperature	T_{STG}	-55 to 150	°C
Thermal Resistance	θ_{JC}	1.5	°C/W

TYPICAL DEVICE IMPEDANCES

F (MHz)	Z_{IN} (Ω)	Z_{LOAD} (Ω)
100	6.0-j20.0	25.0+j27.0
300	2.5-j5.5	13.0+j13.0
500	4.0+j3.0	12.0+j5.0

 $V_{DD}=28V$, $I_{DQ}=500$ mA, $P_{OUT}=40.0$ W

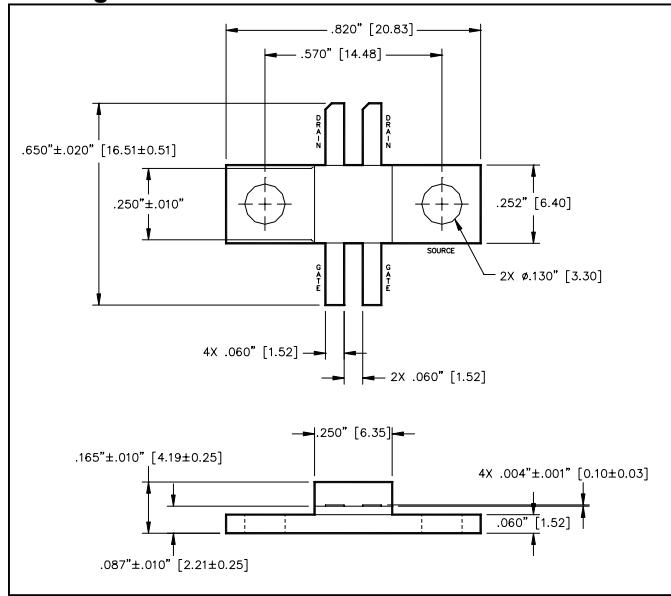
Z_{IN} is the series equivalent input impedance of the device from gate to source.

Z_{LOAD} is the optimum series equivalent load impedance as measured from drain to ground.

ELECTRICAL CHARACTERISTICS AT 25° C

Parameter	Symbol	Min	Max	Units	Test Conditions
Drain-Source Breakdown Voltage	BV_{DSS}	65	-	V	$V_{GS} = 0.0$ V, $I_{DS} = 5.0$ mA
Drain-Source Leakage Current	I_{DSS}	-	1.0	mA	$V_{GS} = 28.0$ V, $V_{DS} = 0.0$ V
Gate-Source Leakage Current	I_{GSS}	-	1.0	μA	$V_{GS} = 20.0$ V, $V_{DS} = 0.0$ V
Gate Threshold Voltage	$V_{GS(TH)}$	2.0	6.0	V	$V_{DS} = 10.0$ V, $I_{DS} = 100.0$ mA
Forward Transconductance	G_M	.5	-	S	$V_{DS} = 10.0$ V, $I_{DS} = 1.0$ A, $\Delta V_{GS} = 1.0$ V, 80 μs Pulse
Input Capacitance	C_{ISS}	-	45	pF	$V_{DS} = 28.0$ V, $F = 1.0$ MHz
Output Capacitance	C_{OSS}	-	30	pF	$V_{DS} = 28.0$ V, $F = 1.0$ MHz
Reverse Capacitance	C_{RSS}	-	8	pF	$V_{DS} = 28.0$ V, $F = 1.0$ MHz
Power Gain	G_P	10	-	dB	$V_{DD} = 28.0$ V, $I_{DQ} = 500.0$ mA, $P_{OUT} = 40.0$ W $F = 500$ MHz
Drain Efficiency	η_D	50	-	%	$V_{DD} = 28.0$ V, $I_{DQ} = 500.0$ mA, $P_{OUT} = 40.0$ W $F = 500$ MHz
Load Mismatch Tolerance	VSWR-T	-	20:1	-	$V_{DD} = 28.0$ V, $I_{DQ} = 500.0$ mA, $P_{OUT} = 40.0$ W $F = 500$ MHz

*Per side

Package Outline

UNLESS OTHERWISE NOTED, TOLERANCES ARE INCHES ±.005" [MILLIMETERS ±0.13mm]

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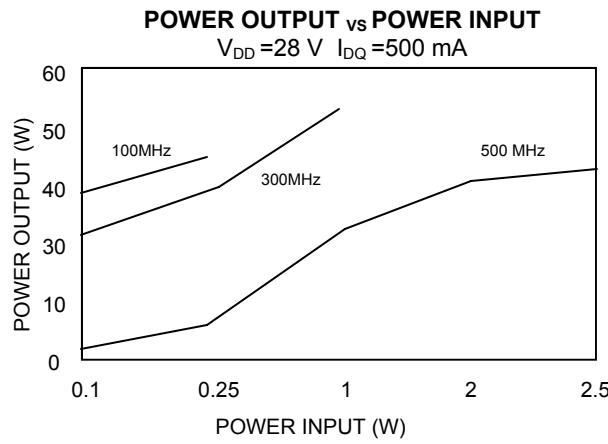
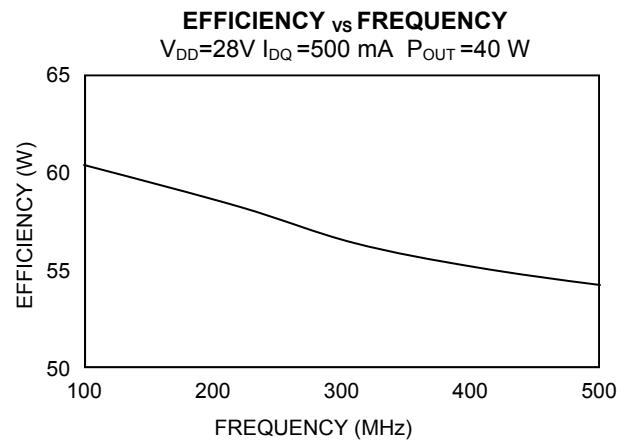
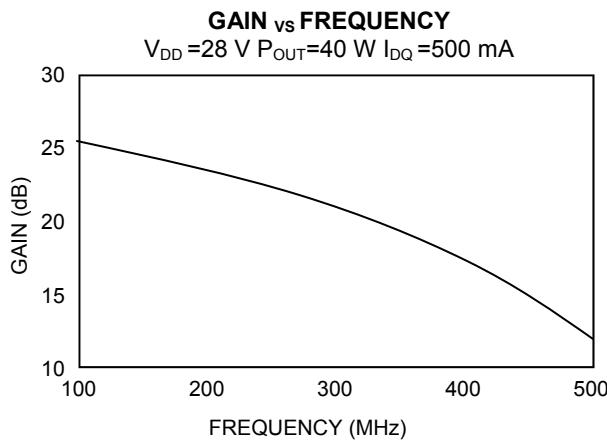
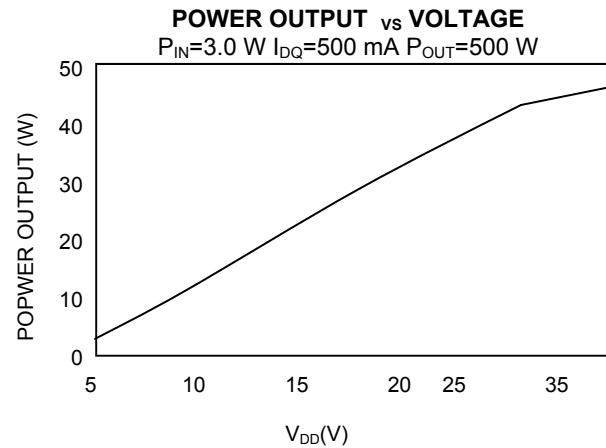
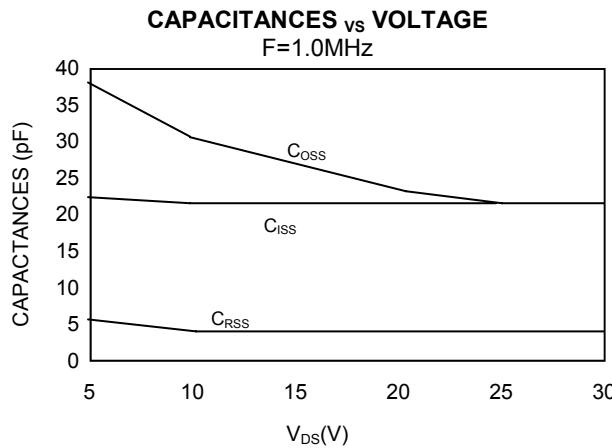
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40W, 100-500 MHz, 28V
M/A-COM Products
Released; RoHS Compliant
Typical Broadband Performance Curves


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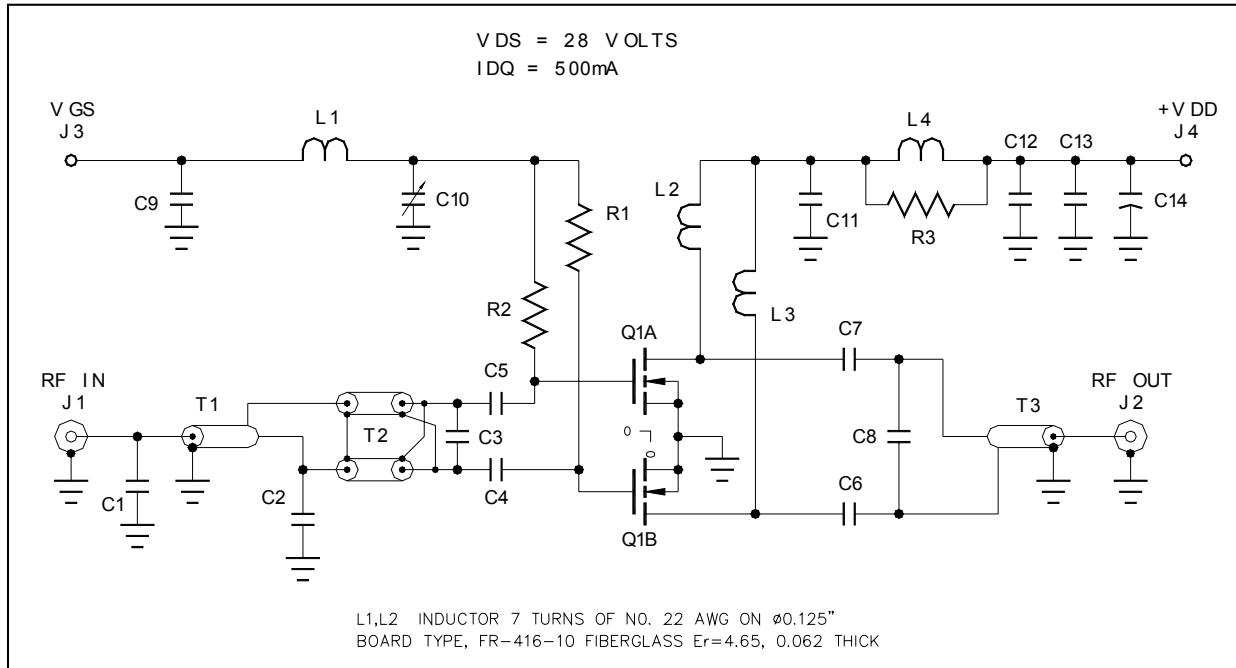
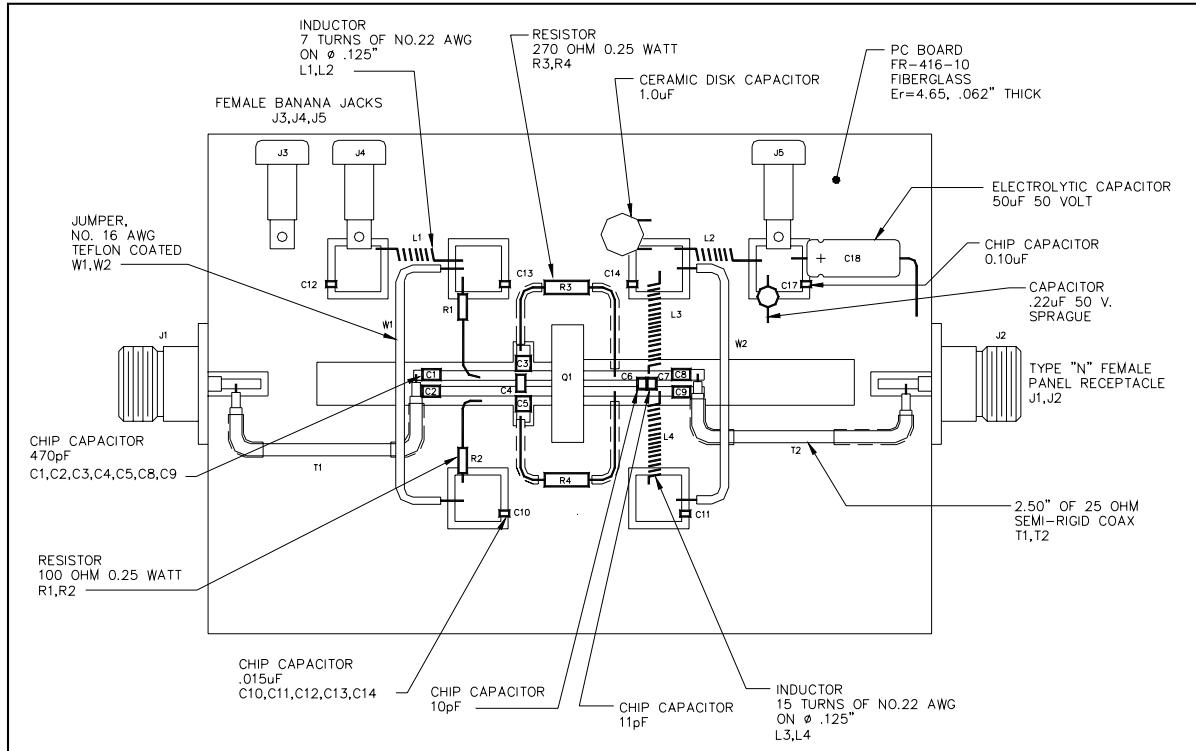
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TEST FIXTURE SCHEMATIC**TEST FIXTURE SCHEMATIC**

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